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Citation for the original published paper (version of record):

Wang, L., Pan, W., Chen, X. et al (2018). Influence of Bi on morphology and optical properties of InAs QDs: Publisher's note. Optical Materials Express, 8(9): 2702-2702.
<http://dx.doi.org/10.1364/OME.8.002702>

N.B. When citing this work, cite the original published paper.



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LIJUAN WANG,^{1,2} WENWU PAN,¹ XIREN CHEN,³ XIAOYAN WU,¹ JUN SHAO,³ AND SHUMIN WANG^{1,4,*}

¹Shanghai Institute of Microsystem and Information Technology, Chinese Academy of Sciences, 865 Chang Ning Road, Shanghai 200050, China

²University of Chinese Academy of Sciences, Beijing 100049, China

³Shanghai Institute of Technical Physics, Chinese Academy of Sciences, 500 Yu Tian Road, Shanghai 200083, China

⁴Department of Microtechnology and Nanoscience, Chalmers University of Technology, Gothenburg 41296, Sweden

*shumin@mail.sim.ac.cn

Abstract: This publisher's note amends the affiliations of [Opt. Mater. Express, 7, 4249].

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References

1. L. Wang, W. Pan, X. Chen, X. Wu, J. Shao, and S. Wang, "Influence of Bi on morphology and optical properties of InAs QDs," Opt. Mater. Express 7(12), 4249–4257 (2017).

The affiliations in this article [1] have been corrected: Lijuan Wang's affiliation has been updated to add the University of Chinese Academy of Sciences. The article was corrected on 15 August 2018.